# Wide band IF detector for PHS and radio remote control units BH4126FV

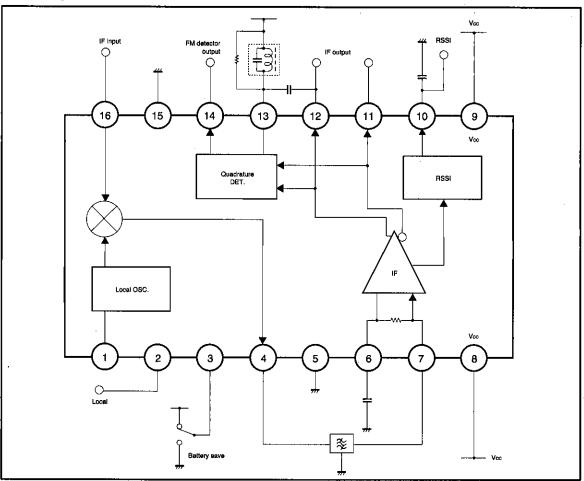
The BH4126FV is an IC equipped with internal mixer, IF amplifier, and FM detector circuits, developed for use with PHS and radio remote control units.

# Applications PHS systems Digital cellular phones Keyless vehicle entry

### Features

- 1) Equipped with internal mixer, IF, RSSI, and FM detection circuits.
- 2) Can be operated at mixer input frequencies ranging from 20MHz to 300MHz.
- 3) Equipped with a battery power saving function.
- 4) Fast RSSI response.

### ●Block diagram



## ●Absolute maximum ratings (Ta=25℃, for measurement circuit)

Parameter	Symbol	Limits	Unit
Power supply voltage	Vcc	7.0	٧
Power dissipation	Po	350 *1	mW
Storage temperature	Tstg	<b>−55∼+125</b>	င

<sup>\*1</sup> Reduced by 3.5 mW for each increase in Ta of 1°C over 25°C.

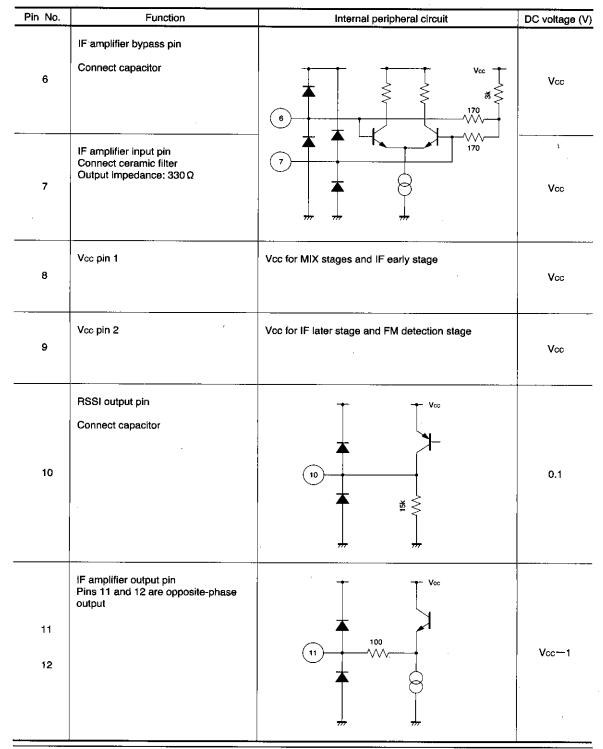
### Recommended operating conditions

Parameter	. Symbol	Limits	Unit
Operating voltage	Vcc	2.3~5.5	٧
Operation temperature	Topr	<b>−40~</b> +85	c

### Pin descriptions

Pin No.	Function	Internal peripheral circuit	DC voltage(V)
1	Local oscillator pin (base)  Connect crystal resonator and capacitor	V <sub>cc</sub>	Vcc-0.6
2	Local oscillator pin (emitter)  Connect capacitor or inject from external oscillator	2 To MIXER	Vcc
3	Battery save pin  "Pin 3 voltage" ≦ 0.2 : Battery save 2 V ≦ "Pin 3 voltage" ≦ Vcc : Active	30k 30k	_
4	Mixer output pin Connect ceramic filter Output impedance: 330 Ω	270 W	Vcc-1.5
5	GND pin	GND for IF stages and FM detection stages	GND

IFs for radio communications



Pln No.	Function	Internal peripheral circuit	DC voltage(V)
13	Discriminator pin  Connect phase compensation coil or ceramic discriminator	500 13	Vec
14	FM demodulation signal output pin Output impedance is 360 Ω	330 Voc	0.9
15	GND pin	GND for MIX stage	GND
16	Mixer pin  Connect first IF signal from DC cutoff	2.4k Vcc	1.0

●Electrical characteristics (Unless otherwise noted, Ta=25°C, Vcc=3.0V;

Signal source :  $f_{\text{IN (MIX)}} = 248.45 \text{MHz}$ ,

 $f_{\text{IN (LO)}} = 237.65 \text{MHz}, 100 \text{dB } \mu \text{V},$ 

AC level to be indicated by termination)

Parameter	Symbol	Min.	Тур,	Max.	Unit	Conditions
Quiescent current	lo.	4.4	5.5	6.6	mA	With local oscillation OFF
Battery save quiescent current	lo (es)	_	0	5	μA	
Dattem and in the territory	V <sub>тнн</sub>	2	T	Vcc	V	Active
Battery save input voltage	V <sub>TH</sub> -L	GND	_	0.2	V	Battery save
MIX - Oscilliator unit		•				,
Mixer operating frequency	fміх	20	-	300	MHz	
Mixer conversion gain	Gvc	16	20	24	dB	V <sub>IN (MIX)</sub> =60dB μ V
-1dB compression output level	Vом	-	103	_	dB μV	
3rd intercept point	IP3	-	110	_	dB μV	f1=248.75MHz,f2=249.05MHz
Noise index	NF		9.7	_	dB	LC matching input
Mixer input admittance	YIN (MIX)	-	1.25+j7.47	_	mS	f=248.45MHz
Mixer output resistance	Во (міх)		330		Ω	
Local oscillator operating frequency	fLO	20	-	120	MHz	
Local input level	Vin (LQ)	95	100	105	dB μV	
Local input admittance	YIN (LQ)		1.36+j9.72	_	mS	f=237.65MHz

Signal source: fin (MIX) = 248.45MHz

 $f_{IN~(LO)} = 237.65MHz,100dB~\mu~V$ 

 $f_{IN (IF)} = 10.8MHz$ 

AC level to be indicated by termination

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
IF unit			-			
IF operating frequency	fıF	4	_	15	MHz	
IF amplifier gain	Gv	_	75		dB	
IF input resistance	Rin (if)	_	330	_	Ω	
IF output level	Voif	0.4	0.5	0.6	V <sub>P-P</sub>	V <sub>IN</sub> (IF) =80dB μV
IF duty ratio	DR	40	50	60	%	Vin (iF) =80dB μV,CL=10pF
RSSI unit			•			
Output voltage 1	Vassii		0.15	0.4	V	No input
Output voltage 2	V <sub>RSSI2</sub>	1.0	1.2	1.4	V	$V_{IN (IF)} = 70 dB \mu V$
Output voltage 3	Vassia	1.8	2.0	2.2	V	V <sub>IN (IF)</sub> =100dB μ V
Dynamic range	DR		70	_	dB	
Output resistance	Ro (ASSI)	12	15	18	kΩ	
Rise time at power on	Ton	_	20	_	μsec	CL=100pF, Vin (MIX) =60dB μ V
Fall time at power off	Toff		5		μsec	CL=100pF, Vin (MIX) =60dB μV
RSSI rise time	TR	_	9	_	μsec	C <sub>L</sub> =100pF, V <sub>IN</sub> (MIX) =60dB μ V
RSSI fall time	TF	_	11	_	μsec	CL=100pF, VIN (MIX) =60dB μV

Signal source :  $f_{\text{IN}} = 10.8 \text{MHz}$ ,  $\Delta f = \pm 10 \text{kHz}$  dev,  $f_{\text{m}} = 1 \text{kHz}$ ;

AC level to be indicated by termination

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Detector unit (for radio rem	ote control)					
Detection sensitivity	SDET		21.2	_	mV / kHz	V <sub>IN (IF)</sub> =80dB μV
Detection output level	Vo	110	150	195	mVrms	$V_{IN (IF)} = 80 dB \mu V$
Detection frequency	foer		100	_	kHz	V <sub>IN (IF)</sub> =80dB μV
12 dB SINAD sensitivity	S (12dB)	12	16	20	dB μV	V <sub>IN (IF)</sub> =80dB μV
S/N ratio	S/N	40	48	_	dB	V <sub>IN (IF)</sub> =80dB μV
AM suppression ratio	AMR	_	40	_	dB	V <sub>IN (IF)</sub> =80dB μV, AM=30%

### Measurement circuit

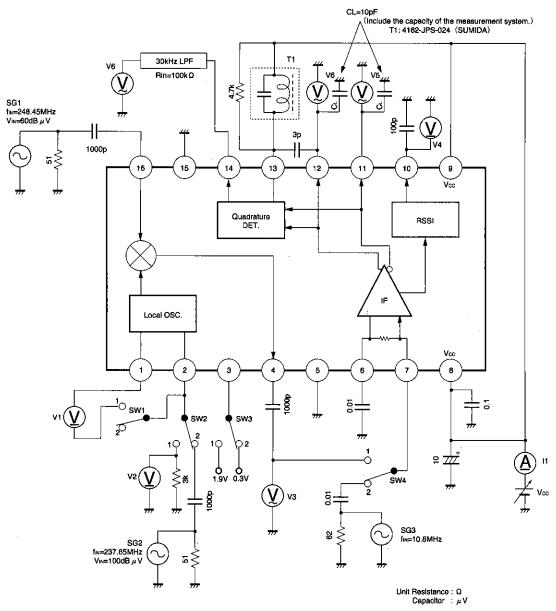
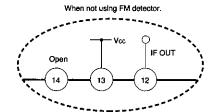


Fig. 1

# ●Application example



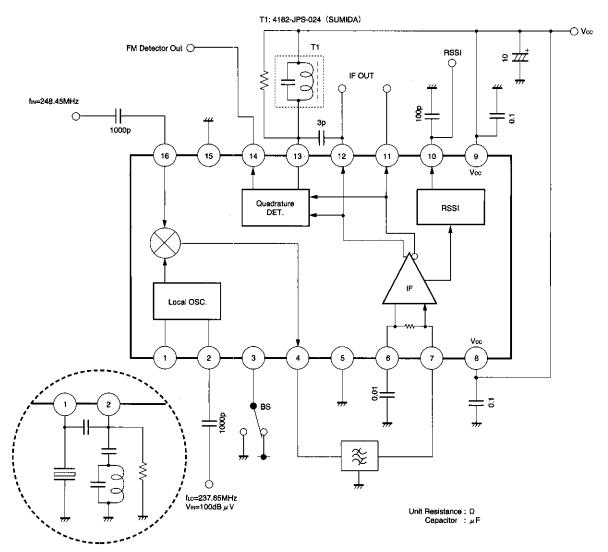
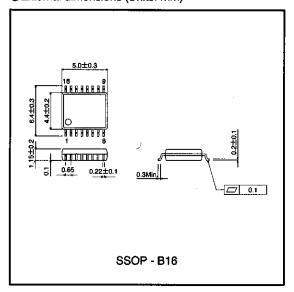


Fig. 2

●External dimensions (Units: mm)



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